

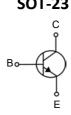
Features

- Collector Current: I_C=0.6A
- Power Dissipation of 300mw



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MMBT2222A	SOT-23	1P	3000



Maxmim Ratings (Ta=25 unless otherwise noted)

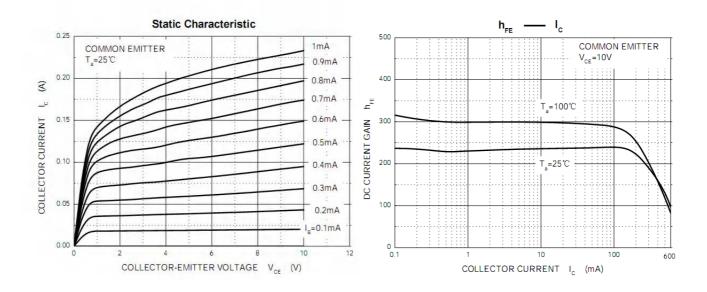
Parameter	Symbol	Limit	Unit	
Collector-Base Voltage	V _{CBO}	75	V	
Collector-Emitter Voltage	V _{CEO}	40	V	
Emitter-Base Voltage	V _{EBO}	6	V	
Collector Current	I _c	600	mA	
Collector Power Dissipation	P _c	300	mW	
Thermal Resistance From Junction To Ambient	R _{OJA}	417	°CW	
Junction Temperature	T _j	150	°C	
Storage Temperature	T _{stg}	-55∼+150	°C	

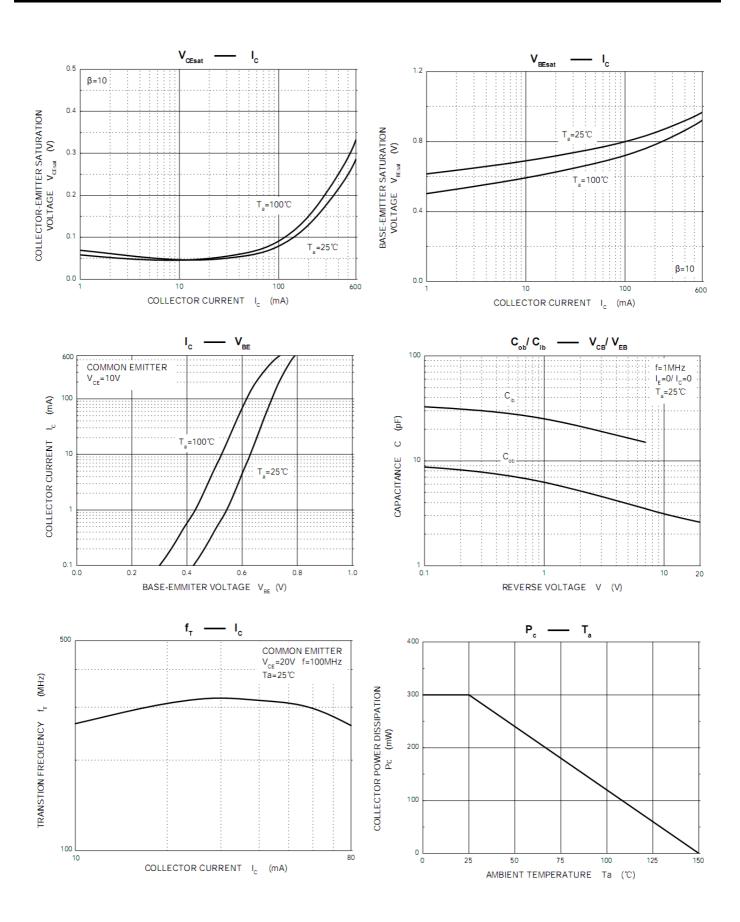
Electrcal Charcteristics (Ta=25 unless otherwise specified)

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Symbol	Test conditions	Min	Тур	Max	Unit
V _{(BR)CBO}	I _C = 10μΑ, I _E =0	75			V
V _{(BR)CEO} *	I _C = 10mA, I _B =0	40			V
$V_{(BR)EBO}$	I _E =10μA, I _C =0	6			V
I _{CBO}	V _{CB} =60V, I _E =0			0.01	μΑ
I _{CEX}	V _{CE} =30V,V _{BE(off)} =3V			0.01	μA
I _{EBO}	V _{EB} = 3V, I _C =0			0.1	μA
h _{FE(1)} *	V _{CE} =10V, I _C = 150mA	100		300	
h _{FE(2)}	V _{CE} =10V, I _C = 0.1mA	40			
h _{FE(3)} *	V _{CE} =10V, I _C = 500mA	42			
V _{CE(sat)} *	I _C =500 mA, I _B = 50mA I _C =150 mA, I _B =15mA			1 0.3	V
V _{BE(sat)} *	I _C =500 mA, I _B = 50mA I _C =150 mA, I _B =15mA			2.0 1.2	٧
f⊤	V _{CE} =20V, I _C = 20mA, f=100MHz	300			MHz
t_d	V _{CC} =30V, V _{BE(off)} =-0.5V			10	ns
t _r	I _C =150mA , I _{B1} = 15mA			25	ns
ts	V _{CC} =30V, I _C =150mA			225	ns
t _f	I _{B1} =-I _{B2} =15mA			60	ns
	V(BR)CBO V(BR)CBO V(BR)EBO ICBO ICEX IEBO hFE(1) hFE(2) hFE(3) VCE(sat) Tt td tr	V _{(BR)CBO} I _C = 10μA, I _E =0 V _{(BR)CEO} * I _C = 10mA, I _B =0 V _{(BR)EBO} I _E =10μA, I _C =0 I _{CBO} V _{CB} =60V, I _E =0 I _{CEX} V _{CE} =30V,V _{BE(off)} =3V I _{EBO} V _{EB} = 3V, I _C =0 h _{FE(1)} * V _{CE} =10V, I _C = 150mA h _{FE(2)} V _{CE} =10V, I _C = 0.1mA h _{FE(3)} * V _{CE} =10V, I _C = 500mA V _{CE} (sat)* I _C =500 mA, I _B =50mA I _C =150 mA, I _B =15mA V _{BE(sat)} * I _C =500 mA, I _B =15mA V _{CE} =20V, I _C =20mA, I _E =100MHz t _d V _{CC} =30V, V _{BE(off)} =-0.5V I _C =150mA, I _B =15mA	V(BR)CBO I _C = 10μA, I _E =0 75 V(BR)CEO I _C = 10mA, I _B =0 40 V(BR)EBO I _E =10μA, I _C =0 6 I _{CBO} V _{CB} =60V, I _E =0 6 I _{CEX} V _{CE} =30V, V _{BE} (off)=3V I _{EBO} V _{EB} =3V, I _C =0 100 h _{FE(1)} V _{CE} =10V, I _C = 150mA 40 h _{FE(2)} V _{CE} =10V, I _C = 0.1mA 40 h _{FE(3)} V _{CE} =10V, I _C = 500mA 42 V _{CE} (sat) I _C =500 mA, I _B =50mA 42 V _{CE} (sat) I _C =500 mA, I _B =15mA 42 V _{DE} (sat) I _C =500 mA, I _B =15mA 43 V _{CE} =20V, I _C =20mA, I _D =15mA 43 44 I _C =150 mA, I _B =15mA 44 45 I _C =150mA, I _B =15mA 45 45	V _{(BR)CBO} I _C = 10μA, I _E =0 75 V _{(BR)CBO} I _C = 10mA, I _B =0 40 V _{(BR)EBO} I _E =10μA, I _C =0 6 I _{CBO} V _{CB} =60V, I _E =0 I _{CEX} V _{CE} =30V,V _{BE(off)} =3V I _{EBO} V _{EB} = 3V, I _C =0 h _{FE(1)} V _{CE} =10V, I _C = 150mA 100 h _{FE(2)} V _{CE} =10V, I _C = 0.1mA 40 h _{FE(3)} V _{CE} =10V, I _C =500mA 42 V _{CE} (sat) I _C =500 mA, I _B =50mA I _C =150 mA, I _B =15mA V _{BE(sat)} I _C =500 mA, I _B =15mA V _{CE} =20V, I _C =20mA, 100mHz t _d V _{CC} =30V, V _{BE(off)} =-0.5V t _r I _C =150mA, I _B =15mA t _s V _{CC} =30V, I _C =150mA	V(BR)CBO Ic= 10μA, I _E =0 75 V(BR)CEO* Ic= 10mA, I _B =0 40 V(BR)EBO I _E =10μA, I _C =0 6 I _{CBO} V _{CB} =60V, I _E =0 0.01 I _{CEX} V _{CE} =30V, V _{BE(off)} =3V 0.01 I _{EBO} V _{EB} =3V, I _C =0 0.1 h _{FE(1)*} V _{CE} =10V, I _C = 150mA 100 300 h _{FE(2)} V _{CE} =10V, I _C = 0.1mA 40 42 h _{FE(3)*} V _{CE} =10V, I _C = 500mA 42 42 V _{CE} =10V, I _C = 500mA 100 0.3 100 V _{CE} (sat)* I _C =500 mA, I _B =15mA 0.3 0.3 V _{BE} (sat)* I _C =500 mA, I _B =15mA 0.3 0.3 I _C =150 mA, I _B =15mA 1.2 0.3 0.3 I _C =150 mA, I _B =15mA 0.3 0.3 0.3 I _C =150mA, I _B =15mA 0.3 0.3 0.3 0.3 I _C =150mA, I _B =15mA 0.3 0.3 0.3 0.3 0.3 0.3 0.3 0.3 0.3 0.3 0.3 0.

^{*}pulse test: Pulse Width ≤300µs, Duty Cycle≤ 2.0%.

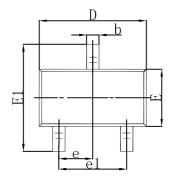
Typical Characteristics

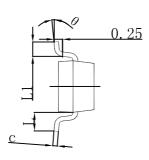


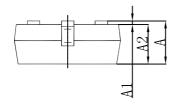




SOT-23 Package Outline Dimensions

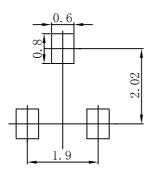




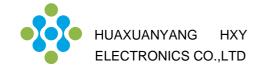


Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
Ш	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
Ш	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



- 1.Controlling dimension:in millimeters. 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.



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